

UNISONIC TECHNOLOGIES CO., LTD

1N5406G **DIODE**

GLASS PASSIVATED SILICON RECTIFIER

DESCRIPTION

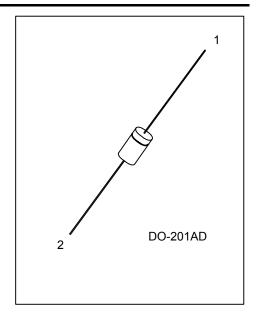
The UTC 1N5406G is a glass passivated silicon rectifier, it uses UTC's advanced technology to provide customers with high forward surge current and low reverse leakage, etc.

FEATURES

- * Low reverse leakage
- * High forward surge current capability

SYMBOL

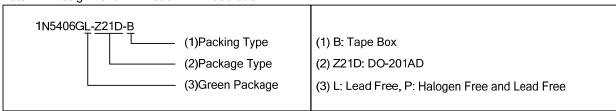




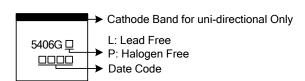
ORDERING INFORMATION

Ordering Number		Dookogo	Pin Assignment		Dooking	
Lead Free	Halogen Free	Package	1	2	Packing	
1N5406GL-Z21D-B	1N5406GP-Z21D-B	DO-201AD	K	Α	Tape Box	

Note: Pin Assignment: A: Anode K: Cathode



MARKING



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ABSOLUTE MAXIMUM RATINGS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

PARAMETER	SYMBOL	RATINGS	UNIT
Working Peak Reverse Voltage	V_{RWM}	600	>
Repetitive Peak Reverse Voltage	V_{RRM}	600	>
RMS Voltage	V_{RMS}	420	V
DC Blocking Voltage	V_{DC}	600	>
Average Forward Rectified Current 0.375" (9.5mm) Lead Length at T _A =75°C	I _(AV)	3.0	Α
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load (JEDEC Method)	I _{FSM}	200	Α
Junction Temperature	TJ	-65~+175	°C
Storage Temperature	T _{STG}	-65~+175	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient (Note 2)	θ_{JA}	20	°C/W

■ ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

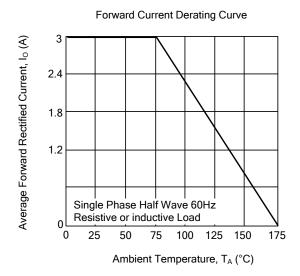
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PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Instantaneous Forward Voltage	V_{F}	I _F =3.0A			1.2	V	
DC Reverse Current at Rated DC Blocking		T _A =25°C			5.0	μΑ	
Voltage	IR	T _A =100°C			100	μA	
Junction Capacitance (Note 1)	CJ			30.0		pF	

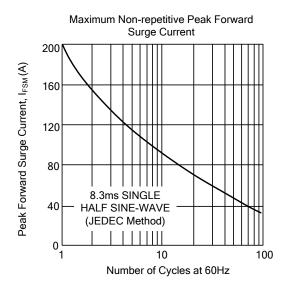
Notes: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

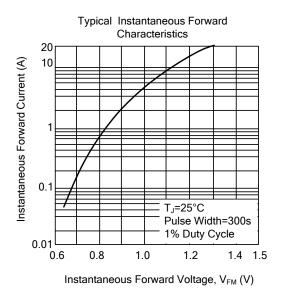
2. Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted.

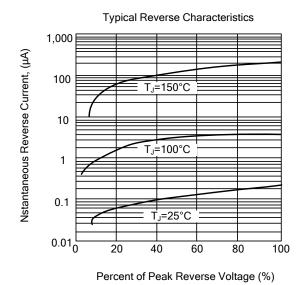
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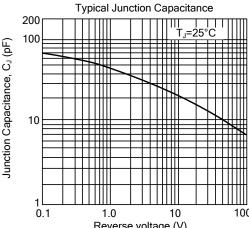
TYPICAL CHARACTERISTICS

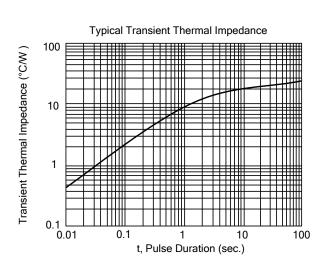












1N5406G

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